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Confinement catalysis of the single atomic vacancy assisted with aliovalent ion doping

enabled efficient NO electroreduction to NH₃

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species	$\Delta E_{ZPE} (eV)$	TΔS (eV)
H ₂ O	0.56	0.67
H_2	0.27	0.40
NO	0.12	0.65
NH ₃	0.89	0.60
*Н	0.19	0.01
*NO	0.20	0.10
*NOH	0.46	0.10
*N	0.10	0.02
*NH	0.42	0.03
*NH ₂	0.74	0.05
* NH ₃	1.03	0.11
*N+*NO	0.27	0.17

Table S1 Zero-point energy corrections and entropic contributions (at 298.15 K) to the free energies.

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TM@MoS _v	PDS	$U_{L}(V)$
Sc	$*NH_2+H^++e^-\rightarrow *NH_3$	-0.70
Ti	$NH_2+H^++e^- \rightarrow NH_3$	-0.60
V	$NH_2+H^++e^- \rightarrow NH_3$	-1.03
Cr	$NH_2+H^++e^- \rightarrow NH_3$	-0.83
Mn	$NH_2+H^++e^- \rightarrow NH_3$	-0.61
Fe	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.58
Со	$NH_2+H^++e^- \rightarrow NH_3$	-0.55
Ni	$NH_2+H^++e \rightarrow NH_3$	-0.39
Cu	$NH_2+H^++e^- \rightarrow NH_3$	-0.41
Y	$NH_2+H^++e^- \rightarrow NH_3$	-0.75
Zr	$NH_2+H^++e^- \rightarrow NH_3$	0.68
Nb	$*NH_2+H^++e^- \rightarrow *NH_3$	-1.18
Мо	*NH+H ⁺ +e ⁻ \rightarrow *NH ₂	-1.55
Тс	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.60
Ru	$NH_2+H^++e^- \rightarrow NH_3$	-0.37
Rh	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.67
Pd	$NH_2+H^++e^- \rightarrow NH_3$	-0.45
Ag	$NH_2+H^++e^- \rightarrow NH_3$	-0.48
La	*NH+H ⁺ +e ⁻ \rightarrow *NH ₂	-0.15
Hf	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.71
Та	$*NH_2+H^++e^- \rightarrow *NH_3$	-1.20
W	$*NH+H^++e^- \rightarrow *NH_2$	-1.59
Re	*NH+H ⁺ +e ⁻ \rightarrow *NH ₂	-0.58
Os	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.26
Ir	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.74
Pt	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.46
Au	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.49

Table S2 The potential-determining steps (PDS) and limiting potential (U_L) for NORR on TM@MoS_v.

Systems	PDS	$U_{L}(V)$
MnO _{2-x} (211)	*NOH+H ⁺ +e ⁻ \rightarrow *N+H ₂ O	-0.271
Zr-C ₂ N	*NO+H ⁺ +e ⁻ →*HNO	-0.29 ²
MoS ₂ (101)	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.30^{3}
NiO (200)	*NO+H ⁺ +e ⁻ →*HNO	-0.14 ⁴
Bi (012)	*NO+H ⁺ +e ⁻ \rightarrow *NOH	-0.665
FeP (202)	$*NH_2+H^++e^- \rightarrow *NH_3$	-0.226
Ru-LCN	*NO+H++e→*HNO	-0.277
Cr_2 - C_2N	*NO+H++e→*HNO	-0.05 ⁸
Co-N ₄ /graphene	*NO+H ⁺ +e ⁻ →*HNO	-0.12 ⁹
Cu@g-C ₃ N ₄	*NO+H ⁺ +e ⁻ →*HNO	-0.37 ¹⁰
Cu@h-BN	*NO+H ⁺ +e ⁻ →*HNO	-0.2311
Nb_2B_2	*NO+H ⁺ +e ⁻ \rightarrow *NOH	-0.11 ¹²
Hf_2B_2	*NO+H ⁺ +e ⁻ →*NOH	-0.17 ¹²
Pt (111)	*NO+H ⁺ +e ⁻ \rightarrow *NOH	-0.2813
Pt (100)	*NO+H ⁺ +e ⁻ →*HNO	-0.3213
Ni ₂ P (111)	*NO+H ⁺ +e ⁻ →*NOH	-0.6114

 $\label{eq:solution} \textbf{Table S3} \ The \ potential-determining \ steps \ (PDS) \ and \ limiting \ potential \ (U_L) \ for \ NORR \ in \ literatures.$



Fig. S1 The local atomic structures of various $TM@MoS_v$. The pictures with the ginger border represent the asymmetric local configurations of $TM@MoS_2$, while the others are the symmetric ones. The red dashed circle indicates the rough position of the S SAV.



Fig. S2 Local atomic structures of NO-adsorbed $TM@MoS_{\nu}.$ The key bond lengths are given.



Fig. S3 The charge density difference (CDD) for two Mo and one La doping in MoS_v . The green and red regions denote the electron accumulation and depletion, respectively, and the isosurface value is set to be 0.01 e/bohr³.



Fig. S4 The binding free energy of NO ($\Delta G(*NO)$) on TM@MoS_v versus the corresponding d-band center (ϵ_d) of TM.



Fig. S5 The N-O bond length of *NO $(d_{(N-O)})$ versus the corresponding numbers of electron transferred to the adsorbed NO (Δq) .























Fig. S6 The LDOS, COHP and CDD for NO adsorption on (a) Ni@MoS_v, (b) Cu@MoS_v, (c) Ru@MoS_v, (d) Pd@MoS_v, (e) Ag@MoS_v, (f) Os@MoS_v, (g) Pt@MoS_v, and (h) Au@MoS_v. In LDOS and COHP, the Fermi level (E_f) is set to 0 eV. In CDD for NO adsorption on various TM@MoS_v, the green and red regions denote the electron accumulation and depletion, respectively, and the isosurface value is set to be 0.01 e/bohr³.



Fig. S7 The NORR limiting potential (U_L) versus the corresponding NH_2 binding free energy ($\Delta G(*NH_2)$).













Fig. S8 Free energy diagrams for NORR on various TM@MoSv.









Fig. S9 Potential-determining steps for NORR on various $TM@MoS_v$ with the local atomic configurations.



Fig. S10 The four considered N adsorption sites near the S vacancy.





Fig. S11 The temperature and total energy variation against time through the AIMD simulation for Ni@MoS_v, Ru@MoS_v, Pd@MoS_v, La@MoS_v, Os@MoS_v and Pt@MoS_v. The simulation was performed under 600 K for 8 ps with a time-step of 1 fs. The top view of the final configuration after the simulation are shown as insets.



Fig. S12 Total densities of states (TDOS) for Ni@MoS_v, Ru@MoS_v, Pd@MoS_v, La@MoS_v, Os@MoS_v and Pt@MoS_v. The E_f is set to be 0 eV.



Fig. S13 Free energy diagrams of NORR on La@MoSv with the solvation correction.



Fig. S14 (a) and (e) are for the total densities of states (TDOS) of the MoS_2 monolayer unit cell. (b) and (f) are for the TDOS of $La@MoS_v$. (c) and (g) are for the TDOS of NO-adsorbed $La@MoS_v$. (d) and (h) are the local densities of states (LDOS) of the *NO, and its bonded La (5d states) and Mo (4d states) of the NO-adsorbed $La@MoS_v$. For (a-d), the PBE functional has been used, while for (e-h) the HSE06 functional has been used.

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